



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## 2SK4087LS — N-Channel Silicon MOSFET — General-Purpose Switching Device Applications

### Features

- ON-resistance  $R_{DS(on)}=0.47\Omega$  (typ.)
- 10V drive
- Input capacitance  $C_{iss}=1200\text{pF}$  (typ.)

### Specifications

Absolute Maximum Ratings at  $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	$V_{DSS}$		600	V
Gate-to-Source Voltage	$V_{GSS}$		$\pm 30$	V
Drain Current (DC)	$I_{Dc}$ *1	Limited only by maximum temperature $T_{ch}=150^\circ\text{C}$	14	A
	$I_{Dpack}$ *2	$T_c=25^\circ\text{C}$ (SANYO's ideal heat dissipation condition)*3	9.2	A
Drain Current (Pulse)	$I_{DP}$	$PW \leq 10\mu\text{s}$ , duty cycle $\leq 1\%$	52	A
Allowable Power Dissipation	PD		2.0	W
		$T_c=25^\circ\text{C}$ (SANYO's ideal heat dissipation condition)*3	40	W
Channel Temperature	$T_{ch}$		150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ\text{C}$
Avalanche Energy (Single Pulse) *4	EAS		106	mJ
Avalanche Current *5	I <sub>AV</sub>		14	A

\*1 Shows chip capability.

\*2 Package limited.

\*3 SANYO's condition is radiation from backside.

The method is applying silicone grease to the backside of the device and attaching the device to water-cooled radiator made of aluminium.

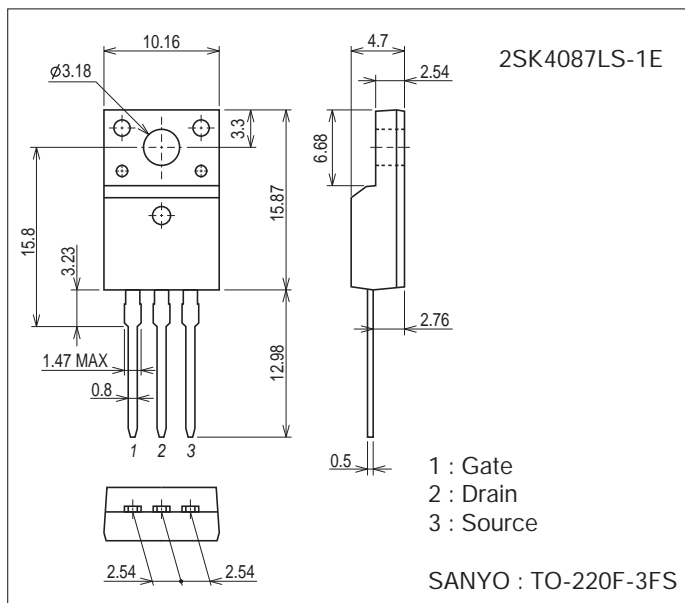
\*4  $V_{DD}=50\text{V}$ ,  $L=1\text{mH}$ ,  $I_{AV}=14\text{A}$  (Fig.1)

\*5  $L \leq 1\text{mH}$ , Single pulse

### Package Dimensions

unit : mm (typ)

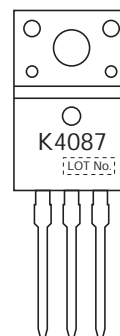
7528-001



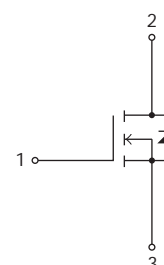
### Product & Package Information

- Package : TO-220F-3FS
- JEITA, JEDEC : SC-67
- Minimum Packing Quantity : 50 pcs./magazine

### Marking



### Electrical Connection



SANYO Semiconductor Co., Ltd.

<http://www.sanyosemi.com/en/network/>

# 2SK4087LS

## Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=10mA, VGS=0V	600			V
Zero-Gate Voltage Drain Current	IDSS	VDS=480V, VGS=0V			100	μA
Gate-to-Source Leakage Current	IGSS	VGS=±30V, VDS=0V			±100	nA
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	3		5	V
Forward Transfer Admittance	yfs	VDS=10V, ID=7A	4	8		S
Static Drain-to-Source On-State Resistance	RDS(on)	ID=7A, VGS=10V		0.47	0.61	Ω
Input Capacitance	Ciss	VDS=30V, f=1MHz		1200		pF
Output Capacitance	Coss			220		pF
Reverse Transfer Capacitance	Crss			50		pF
Turn-ON Delay Time	td(on)	See Fig.2		27		ns
Rise Time	tr			72		ns
Turn-OFF Delay Time	td(off)			144		ns
Fall Time	tf			48		ns
Total Gate Charge	Qg				46	
Gate-to-Source Charge	Qgs	VDS=200V, VGS=10V, ID=14A		8.6		nC
Gate-to-Drain "Miller" Charge	Qgd			26.4		nC
Diode Forward Voltage	VSD	IS=14A, VGS=0V		0.95	1.3	V

Fig.1 Unclamped Inductive Switching Test Circuit

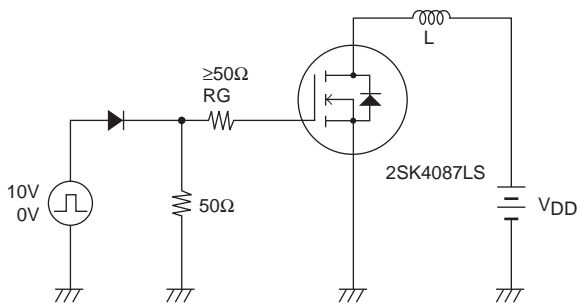
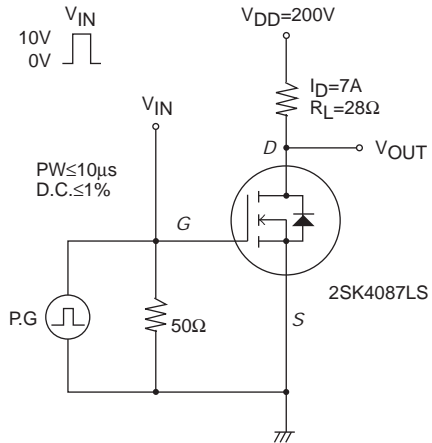
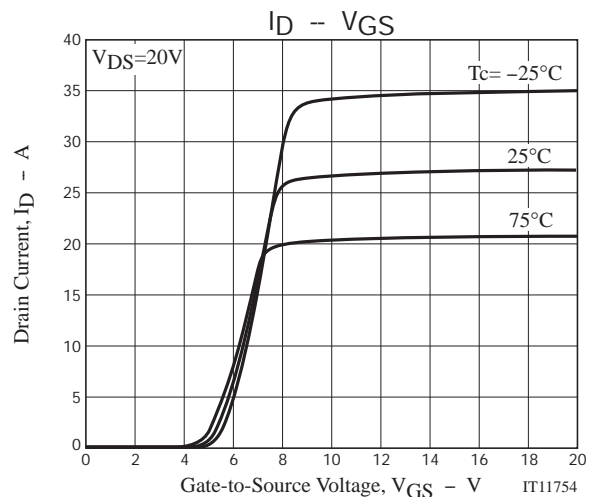
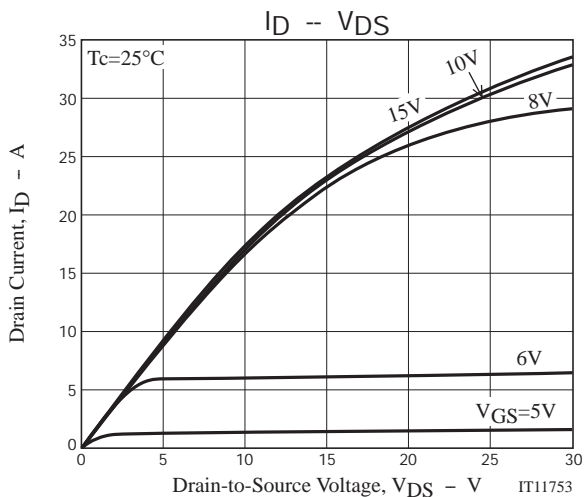


Fig.2 Switching Time Test Circuit

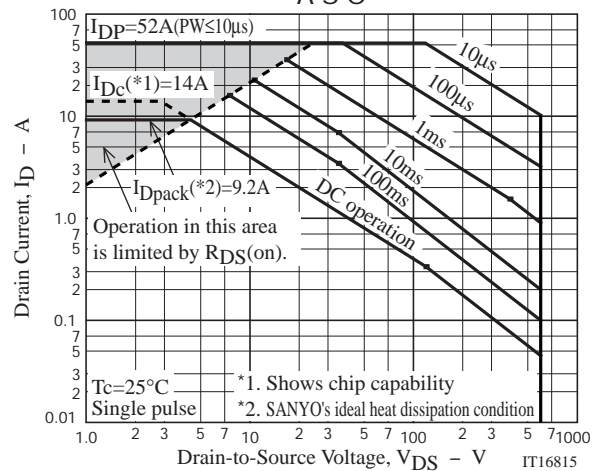
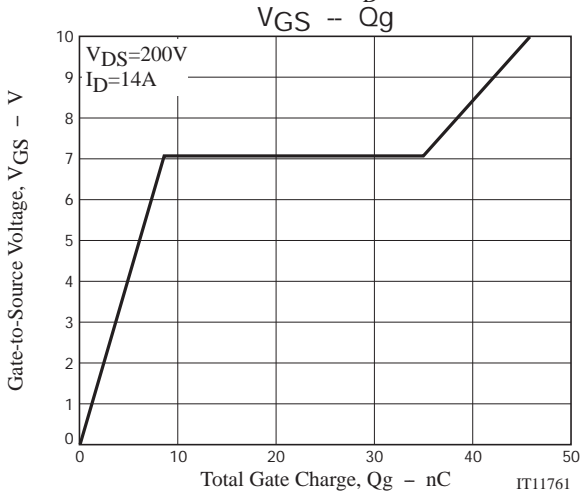
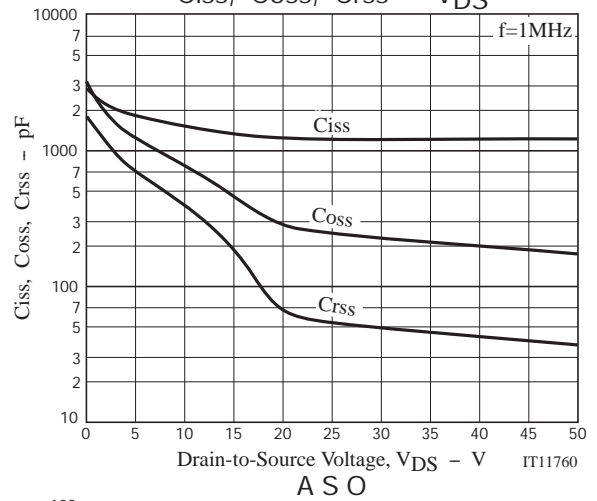
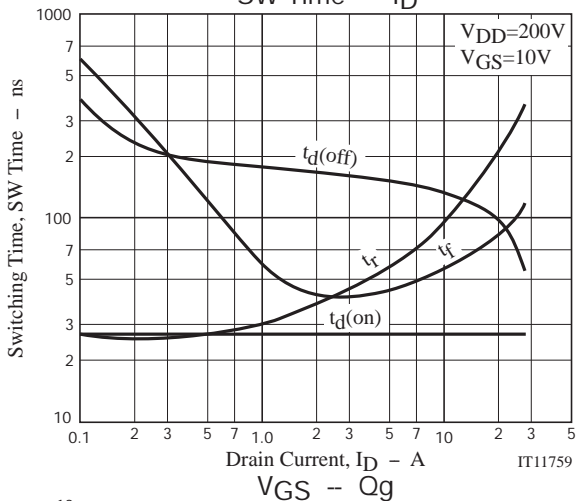
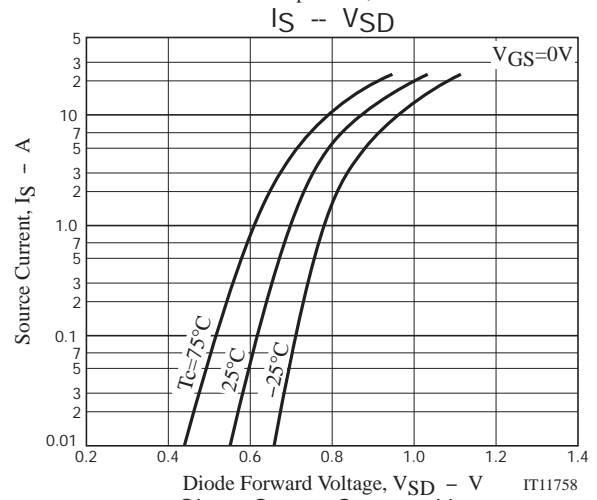
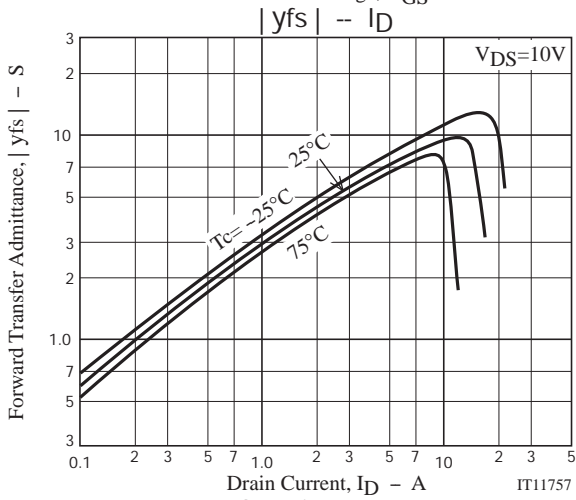
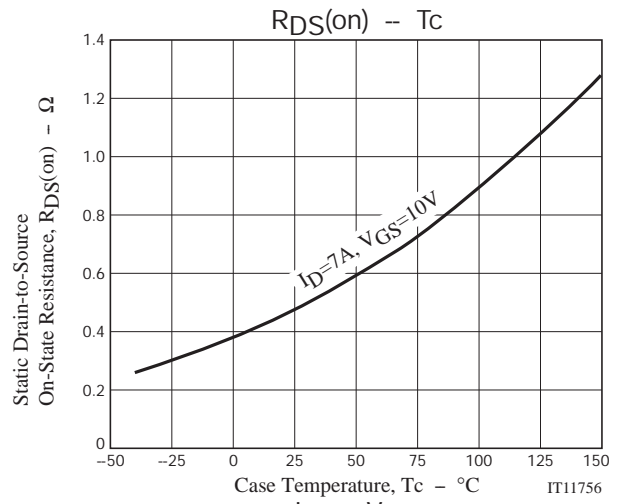
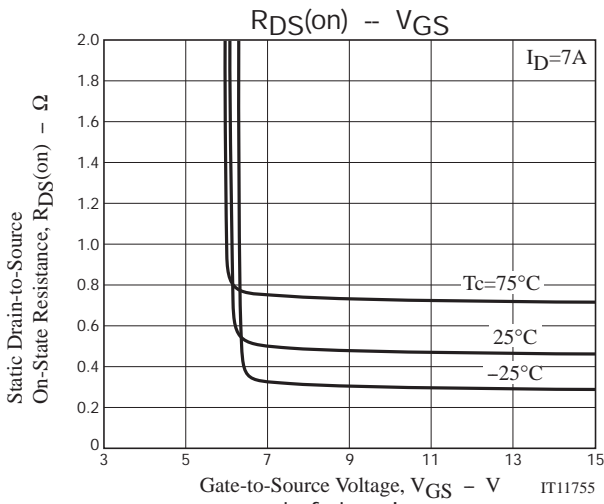


## Ordering Information

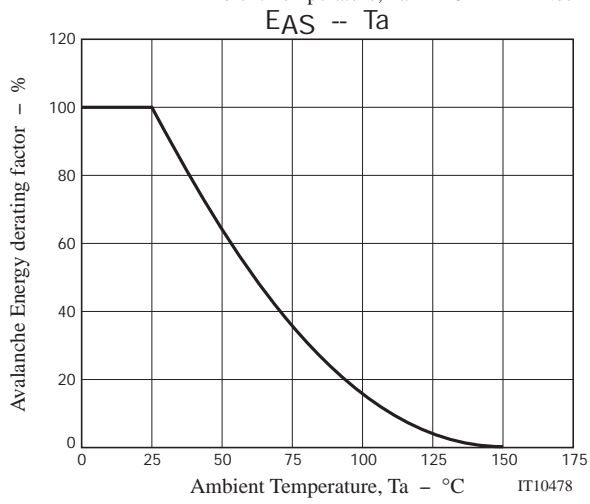
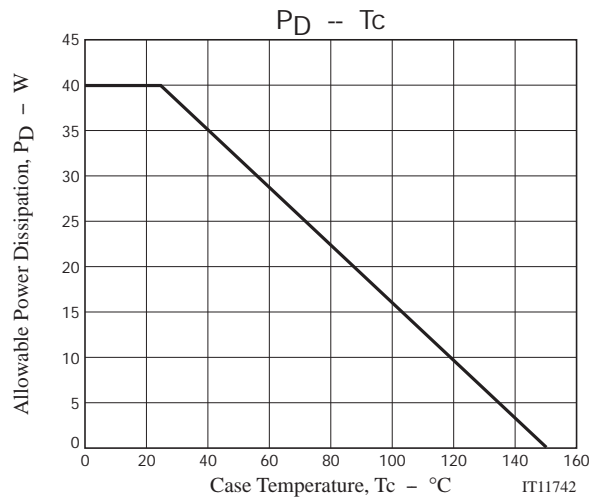
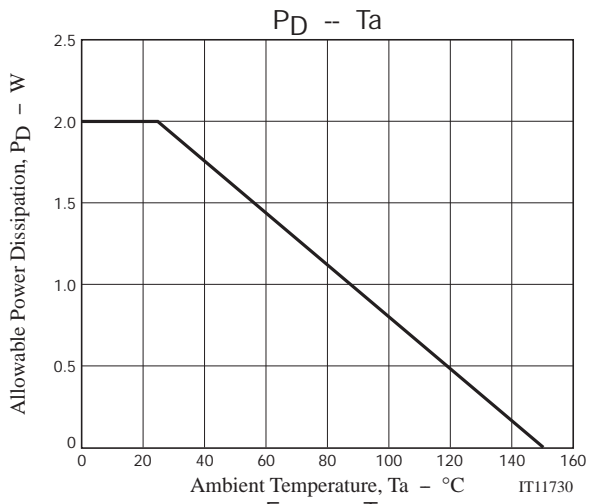
Device	Package	Shipping	memo
2SK4087LS-1E	TO-220F-3FS	50pcs./magazine	Pb Free



# 2SK4087LS



# 2SK4087LS



# 2SK4087LS

## Magazine Specification

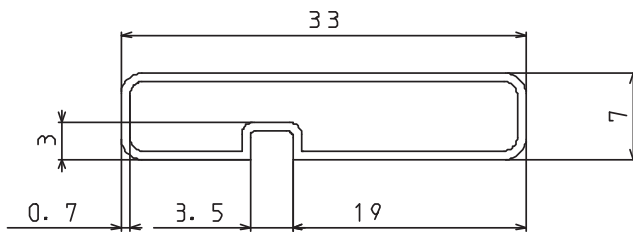
2SK4087LS-1E

### 1. Packing Format

Package Name	Magazine Name	Maximum Number of devices contained (pcs)			Packing format	
		Magazine	Inner box	Outer box	Inner BOX	Outer BOX
TO-220F-3FS	TO-220F	50	1,000	4,000	SPD-0V0001 20 magazines contained Dimensions:mm (external) 568×150×55	SPT-081029 4 inner boxes contained Dimensions:mm (external) 590×225×178

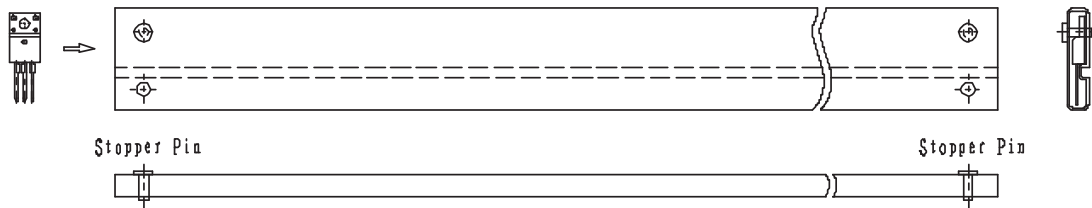
### 2. Magazine dimensions

(unit:mm)

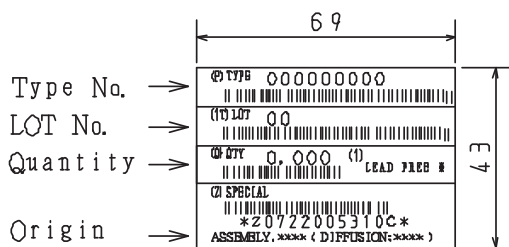


Tolerance=±0.3mm  
 Thickness=0.7±0.2mm  
 Length =532.5±2mm  
 Material =PVC (Antistatic treatment)

### 3. Storage method to magazine

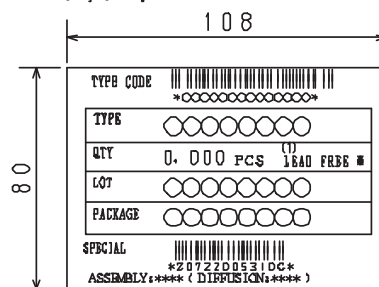


### 4. Inner box label (unit:mm)



### 5. Outer box label (unit:mm)

It is a label at the time of factory shipments.  
 The form of a label may change in physical  
 distribution process.



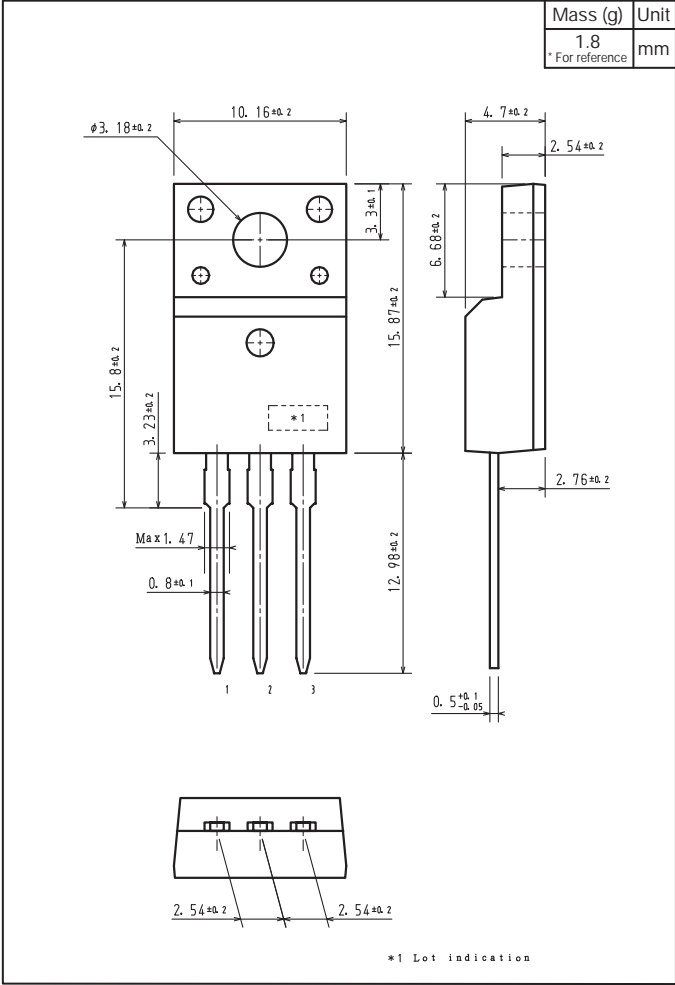
#### NOTE (1)

The LEAD FREE \* description shows that the  
 surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A

2SK4087LS

Outline Drawing  
2SK4087LS-1E



Note on usage : Since the 2SK4087LS is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment. The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for new introduction or other application different from current conditions on the usage of automotive device, communication device, office equipment, industrial equipment etc. , please consult with us about usage condition (temperature, operation time etc.) prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- Regarding monolithic semiconductors, if you should intend to use this IC continuously under high temperature, high current, high voltage, or drastic temperature change, even if it is used within the range of absolute maximum ratings or operating conditions, there is a possibility of decrease reliability. Please contact us for a confirmation.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of October, 2012. Specifications and information herein are subject to change without notice.